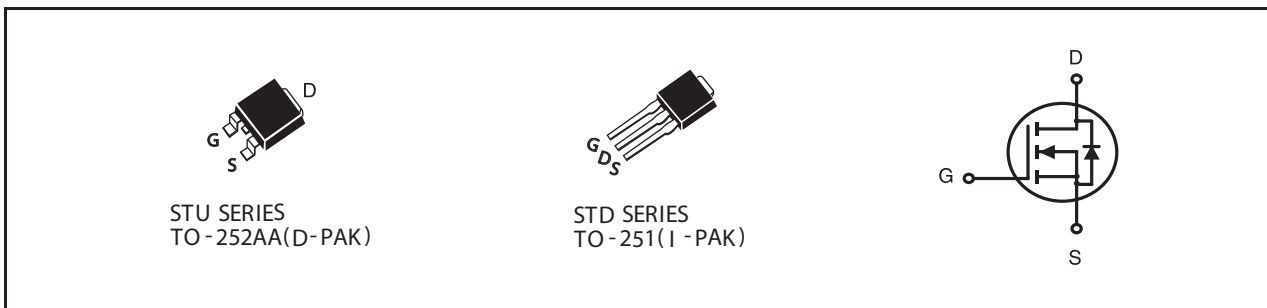


**N-Channel Logic Level Enhancement Mode Field Effect Transistor****PRODUCT SUMMARY**

VDSS	ID	RDS(ON) (mΩ) Max
40V	50A	9 @ VGS=10V
		11 @ VGS=4.5V

FEATURES

- Super high dense cell design for low $R_{DS(ON)}$.
- Rugged and reliable.
- TO-252 and TO-251 Package.

**ABSOLUTE MAXIMUM RATINGS** ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Limit	Units
V_{DS}	Drain-Source Voltage	40	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous ^a	$T_C=25^{\circ}\text{C}$	50
		$T_C=70^{\circ}\text{C}$	40
I_{DM}	-Pulsed ^b	147	A
I_{AS}	Single Pulse Avalanche Current ^c	23	A
E_{AS}	Single Pulse Avalanche Energy ^c	132	mJ
P_D	Maximum Power Dissipation ^a	$T_C=25^{\circ}\text{C}$	42
		$T_C=70^{\circ}\text{C}$	27
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 175	$^{\circ}\text{C}$

THERMAL CHARACTERISTICS

$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	3	$^{\circ}\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	50	$^{\circ}\text{C}/\text{W}$

STU/D438S

Ver 1.3

ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	40			V
BV _{DSS}	Drain-Source Breakdown Voltage ^d	V _{GS} =0V , I _D =10mA	45			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =32V , V _{GS} =0V			1	uA
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V , V _{DS} =0V			±100	nA
ON CHARACTERISTICS ^a						
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250uA	1.5	1.7	3	V
R _{DS(ON)}	Drain-Source On-State Resistance	V _{GS} =10V , I _D =25A		7	9	m ohm
		V _{GS} =4.5V , I _D =23A		8.5	11	m ohm
g _{FS}	Forward Transconductance	V _{DS} =5V , I _D =25A		60		S
DYNAMIC CHARACTERISTICS ^b						
C _{ISS}	Input Capacitance	V _{DS} =20V, V _{GS} =0V f=1.0MHz		1380		pF
C _{OSS}	Output Capacitance			250		pF
C _{RSS}	Reverse Transfer Capacitance			155		pF
SWITCHING CHARACTERISTICS ^b						
t _{D(ON)}	Turn-On Delay Time	V _{DD} =20V I _D =1A V _{GS} =10V R _{GEN} = 6 ohm		21		ns
t _r	Rise Time			25		ns
t _{D(OFF)}	Turn-Off Delay Time			66		ns
t _f	Fall Time			36		ns
Q _g	Total Gate Charge	V _{DS} =20V, I _D =25A, V _{GS} =10V		26		nC
		V _{DS} =20V, I _D =25A, V _{GS} =4.5V		12		nC
Q _{gs}	Gate-Source Charge	V _{DS} =20V, I _D =25A, V _{GS} =10V		2.5		nC
Q _{gd}	Gate-Drain Charge			6.6		nC
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
I _S	Maximum Continuous Drain-Source Diode Forward Current				6	A
V _{SD}	Diode Forward Voltage ^a	V _{GS} =0V, I _S =6A		0.78	1.3	V

Notes

- a. Pulse Test: Pulse Width ≤ 300us, Duty Cycle ≤ 2%.
b. Guaranteed by design, not subject to production testing.
c. Starting T_J=25°C, L=0.5mH, V_{DD} = 20V. (See Figure13)
d. Pulse Test: Pulse Width ≤ 1us, Duty Cycle ≤ 1%.

July, 30, 2009

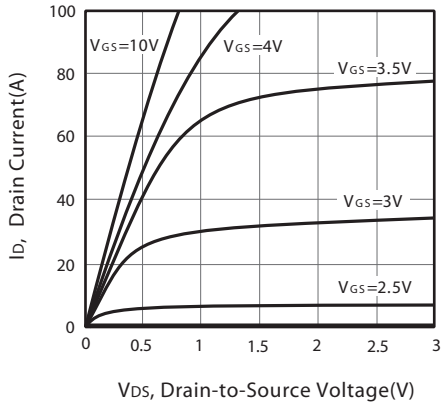


Figure 1. Output Characteristics

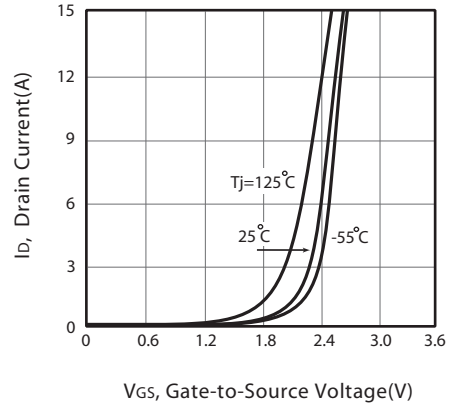


Figure 2. Transfer Characteristics

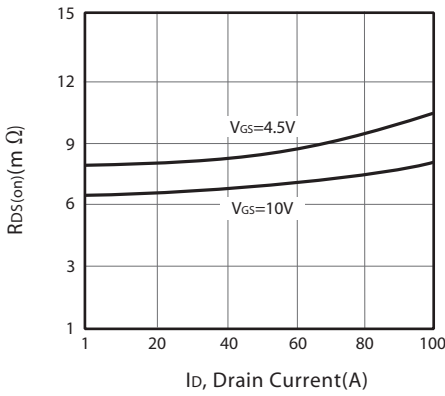


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

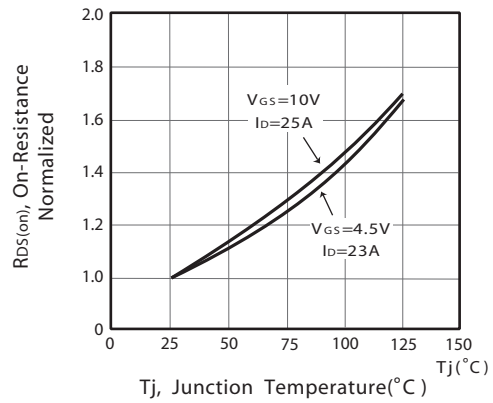


Figure 4. On-Resistance Variation with Drain Current and Temperature

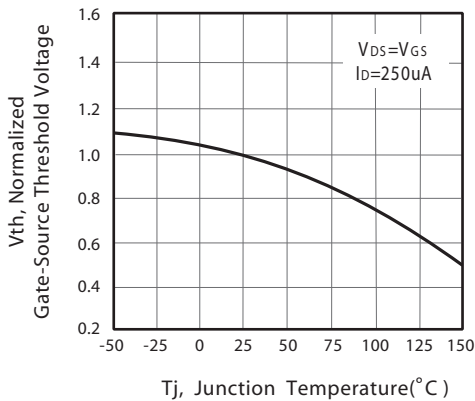


Figure 5. Gate Threshold Variation with Temperature

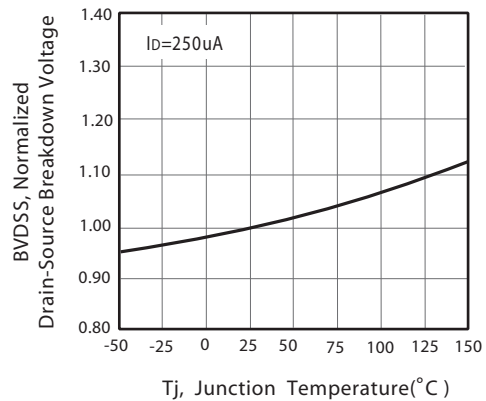


Figure 6. Breakdown Voltage Variation with Temperature

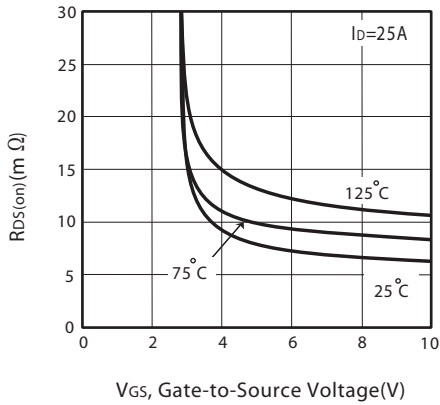


Figure 7. On-Resistance vs. Gate-Source Voltage

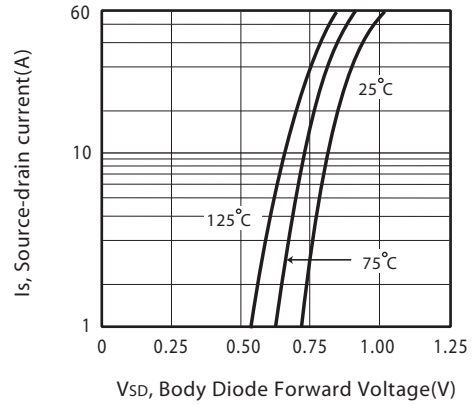


Figure 8. Body Diode Forward Voltage Variation with Source Current

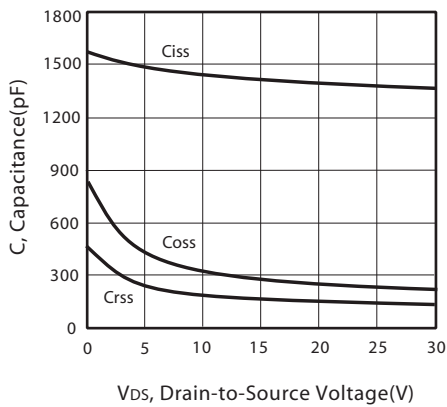


Figure 9. Capacitance

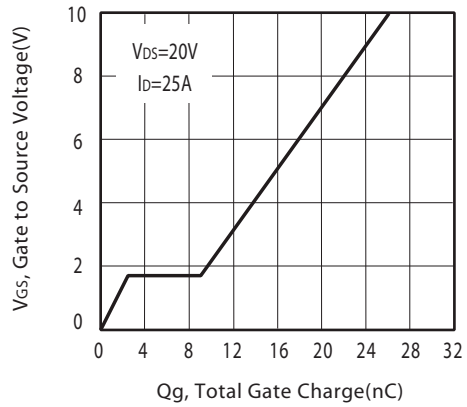


Figure 10. Gate Charge

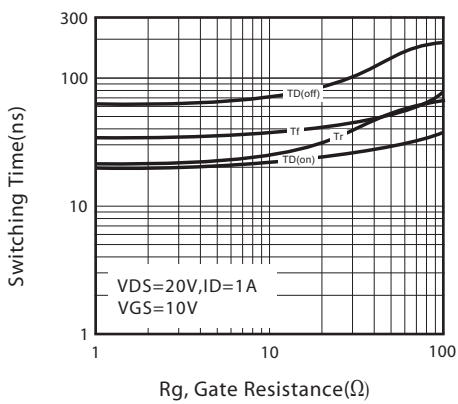


Figure 11. switching characteristics

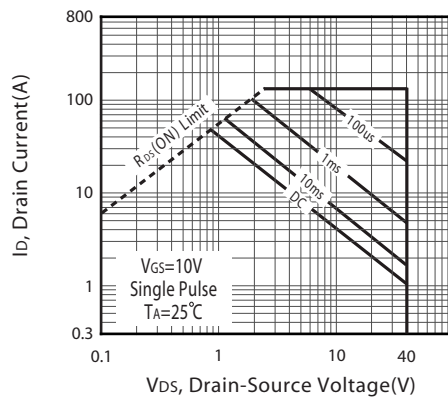
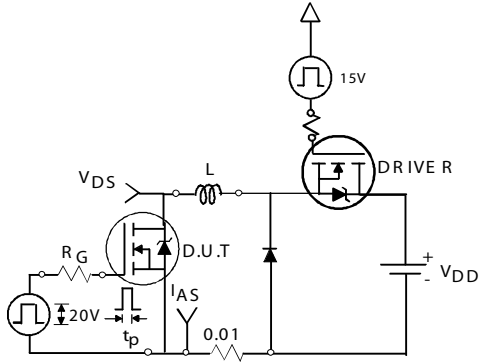
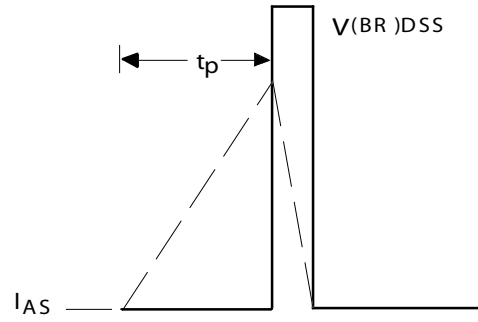


Figure 12. Maximum Safe Operating Area



Unclamped Inductive Test Circuit

Figure 13a.



Unclamped Inductive Waveforms

Figure 13b.

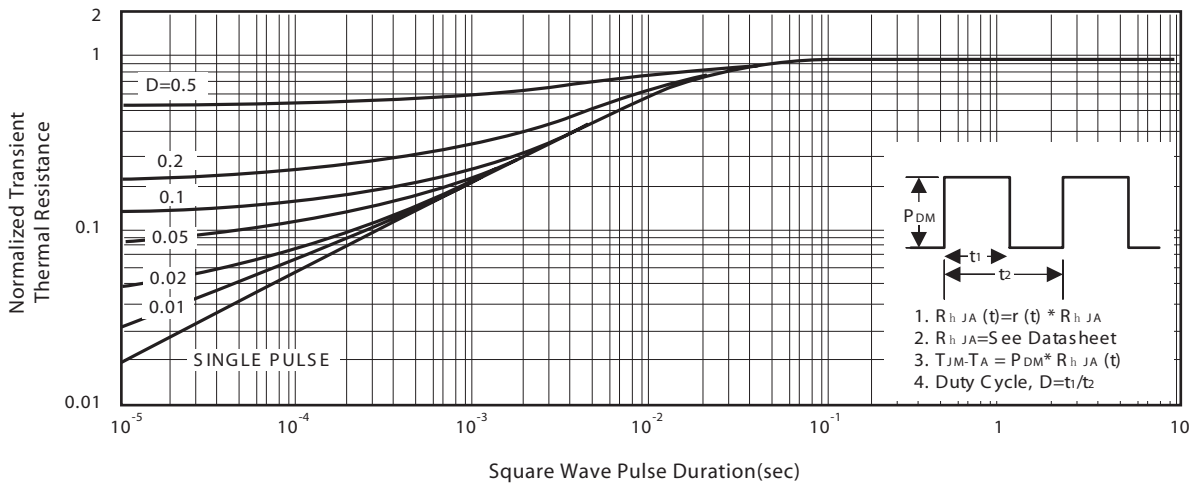
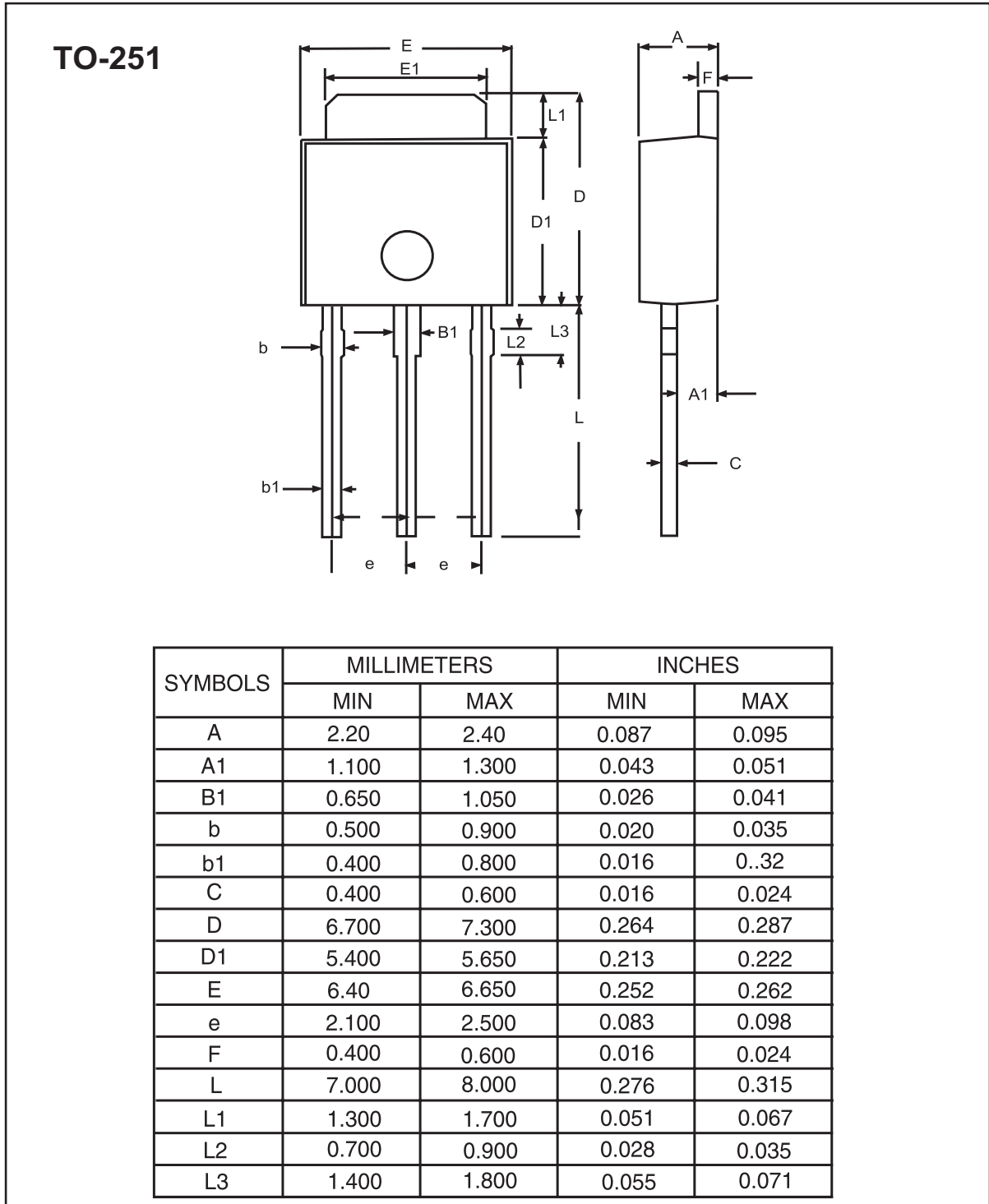


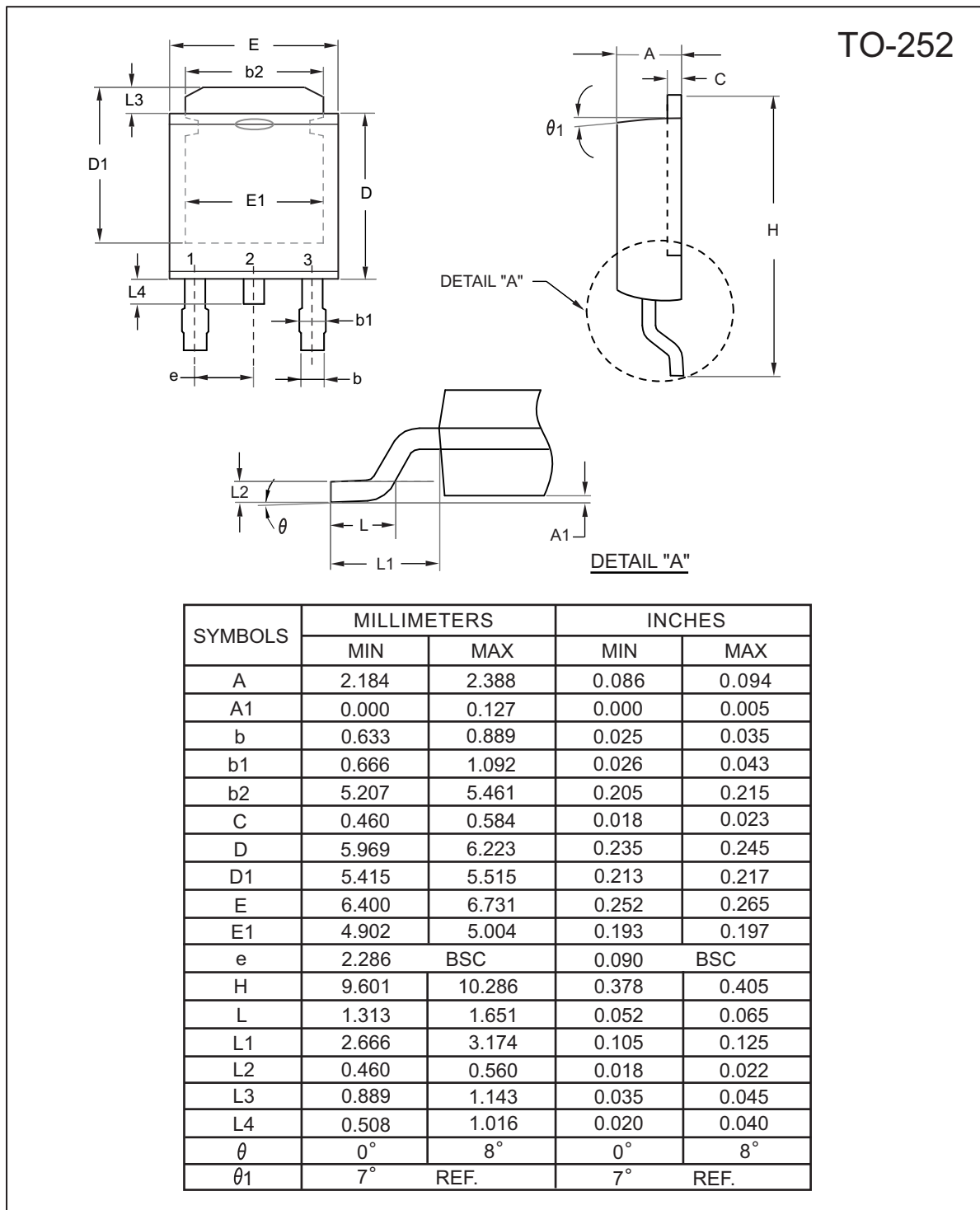
Figure 14. Normalized Thermal Transient Impedance Curve

PACKAGE OUTLINE DIMENSIONS



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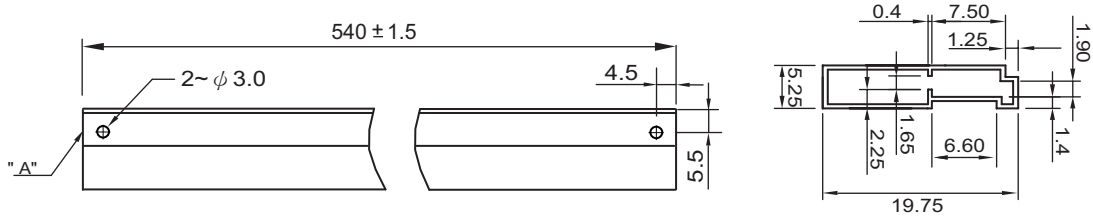
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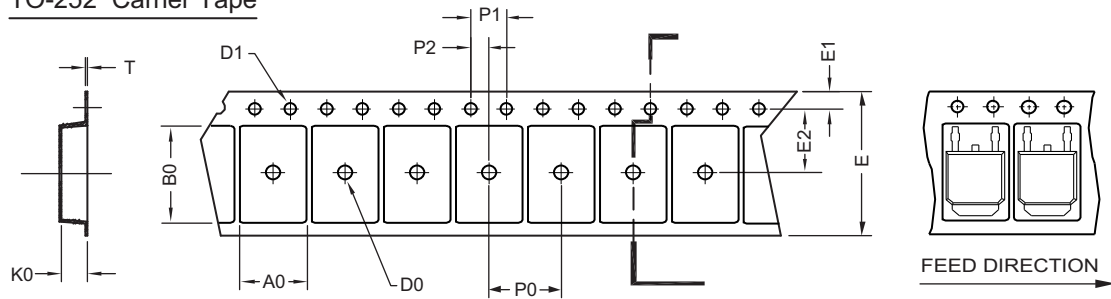
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TO-251 Tube/TO-252 Tape and Reel Data

TO-251 Tube



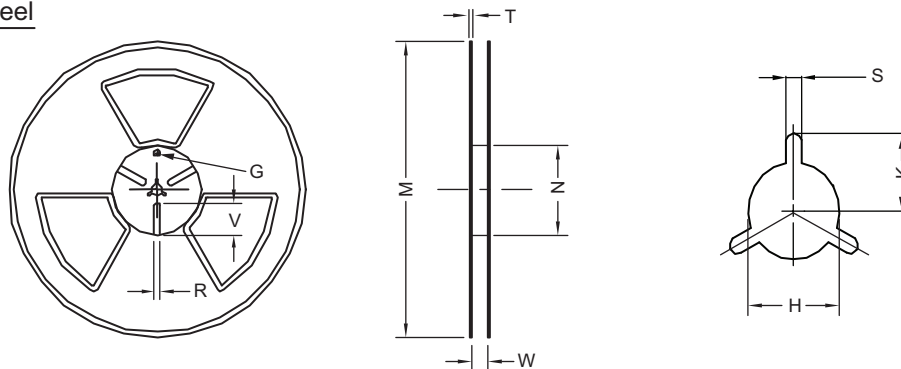
TO-252 Carrier Tape



UNIT:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
TO-252 (16 mm)	6.96 ±0.1	10.49 ±0.1	2.79 ±0.1	φ 2	φ 1.5 + 0.1 - 0	16.0 ±0.3	1.75 ±0.1	7.5 ±0.15	8.0 ±0.1	4.0 ±0.1	2.0 ±0.15	0.3 ±0.05

TO-252 Reel



UNIT:mm

TAPE SIZE	REEL SIZE	M	N	W	T	H	K	S	G	R	V
16 mm	φ 330	φ 330 ± 0.5	φ 97 ± 1.0	17.0 + 1.5 - 0	2.2	φ 13.0 + 0.5 - 0.2	10.6	2.0 ±0.5	---	---	---